

## ISL84581

Low-Voltage, Single and Dual Supply, 8-to-1 Multiplexer

FN6416  
Rev 3.00  
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The Intersil ISL84581 device contains precision, bidirectional, analog switches configured as an 8-to-1 multiplexer/demultiplexer. It was designed to operate from a single +2V to +12V single supply or from dual  $\pm 2V$  to  $\pm 6V$  supplies. The device has an inhibit pin to simultaneously open all signal paths.

The ISL84581 has an ON-resistance of  $39\Omega$  with a dual  $\pm 5V$  supply and  $125\Omega$  with a single +3.3V supply. Each switch can handle rail-to-rail analog signals. The off-leakage current is only 0.02nA at +25°C or 0.2nA at +85°C.

All digital inputs have 0.8V to 2.4V logic thresholds, ensuring TTL/CMOS logic compatibility when using a single 3.3V or +5V supply or dual  $\pm 5V$  supplies.

The ISL84581 is a single 8-to-1 multiplexer device. Table 1 summarizes the performance of the part.

**TABLE 1. FEATURES AT A GLANCE**

CONFIGURATION	SINGLE 8:1 MUX
$\pm 5V$ $r_{ON}$	$39\Omega$
$\pm 5V$ $t_{ON}/t_{OFF}$	32ns/18ns
12V $r_{ON}$	$32\Omega$
12V $t_{ON}/t_{OFF}$	23ns/15ns
5V $r_{ON}$	$65\Omega$
5V $t_{ON}/t_{OFF}$	38ns/19ns
3.3V $r_{ON}$	$125\Omega$
3.3V $t_{ON}/t_{OFF}$	70ns/32ns
Package	16 Ld TSSOP, 16 Ld QSOP

### Related Literature

- Technical Brief TB363 "Guidelines for Handling and Processing Moisture Sensitive Surface Mount Devices (SMDs)"
- Application Note AN557 "Recommended Test Procedures for Analog Switches"
- Application Note AN520 "CMOS Analog Multiplexers and Switches; Specifications and Application Considerations."
- Application Note AN1034 "Analog Switch and Multiplexer Applications"

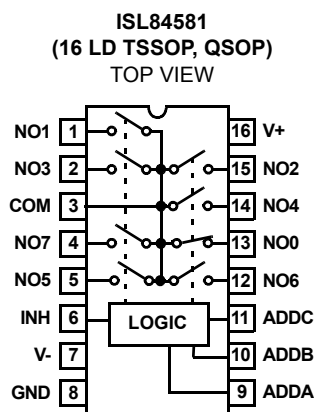
### Features

- Fully Specified at 3.3V, 5V,  $\pm 5V$ , and 12V Supplies for 10% Tolerances
- ON-Resistance ( $r_{ON}$ ) Max,  $V_S = \pm 4.5V$  .....  $50\Omega$
- ON-Resistance ( $r_{ON}$ ) Max,  $V_S = +3V$  .....  $155\Omega$
- $r_{ON}$  Matching Between Channels,  $V_S = \pm 5V$  .....  $<2\Omega$
- Low Charge Injection,  $V_S = \pm 5V$  ..... 1pC (Max)
- Single Supply Operation ..... +2V to +12V
- Dual Supply Operation .....  $\pm 2V$  to  $\pm 6V$
- Fast Switching Action ( $V_S = +5V$ )
  - $t_{ON}$  ..... 38ns
  - $t_{OFF}$  ..... 19ns
- Guaranteed Max Off-leakage ..... 2.5nA
- Guaranteed Break-Before-Make
- TTL, CMOS Compatible
- Pb-free (RoHS Compliant)

### Applications

- Battery Powered, Handheld, and Portable Equipment
- Communications Systems
  - Radios
  - Telecom Infrastructure
  - ADSL, VDSL Modems
- Test Equipment
  - Medical Ultrasound
  - Magnetic Resonance Image
  - CT and PET Scanners (MRI)
  - ATE
  - Electrocardiograph
- Audio and Video Signal Routing
- Various Circuits
  - +3V/+5V DACs and ADCs
  - Sample and Hold Circuits
  - Operational Amplifier Gain Switching Networks
  - High Frequency Analog Switching
  - High Speed Multiplexing
  - Integrator Reset Circuits

## Pinout



NOTE: Switches Shown for Logic "0" Inputs.

## Truth Tables

ISL84581				
INH	ADDC	ADDB	ADDA	SWITCH ON
0	0	0	0	NO0
0	0	0	1	NO1
0	0	1	0	NO2
0	0	1	1	NO3
0	1	0	0	NO4
0	1	0	1	NO5
0	1	1	0	NO6
0	1	1	1	NO7
1	X	X	X	NONE

NOTE: Logic "0"  $\leq 0.8V$ . Logic "1"  $\geq 2.4V$ , with V+ between 2.7V and 10V. X = Don't Care.

## Pin Descriptions

PIN	FUNCTION
V+	Positive Power Supply Input
V-	Negative Power Supply Input. Connect to GND for Single Supply Configurations.
GND	Ground Connection
INH	Digital Control Input. Connect to GND for Normal Operation. Connect to V+ to turn all switches off.
ADDx	Address Input Pin
COM	Analog Switch Common Pin
NOx	Analog Switch Normally Open Pin

## Ordering Information

PART NUMBER (Note)	PART MARKING	TEMP RANGE (°C)	PACKAGE (Pb-free)	PKG. DWG. #
ISL84581IVZ	84581 IVZ	-40 to +85	16 Ld TSSOP (4.4mm)	M16.173
ISL84581IVZ-T*	84581 IVZ	-40 to +85	16 Ld TSSOP (4.4mm) Tape and Reel	M16.173
ISL84581IAZ	84581 IAZ	-40 to +85	16 Ld QSOP (4.4mm)	M16.15A
ISL84581IAZ-T*	84581 IAZ	-40 to +85	16 Ld QSOP (4.4mm) Tape and Reel	M16.15A

\* Please refer to TB347 for details on reel specifications.

NOTE: These Intersil Pb-free plastic packaged products employ special Pb-free material sets, molding compounds/die attach materials, and 100% matte tin plate plus anneal (e3 termination finish, which is RoHS compliant and compatible with both SnPb and Pb-free soldering operations). Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.

**Absolute Maximum Ratings**

V+ to V-	-0.3V to 15V
V+ to GND	-0.3V to 15V
V- to GND	-15V to 0.3V
Input Voltages	
INH, NOx, ADDx (Note 1)	-0.3 to ((V+) + 0.3V)
Output Voltages	
COM (Note 1)	-0.3 to ((V+) + 0.3V)
Continuous Current (Any Terminal)	±30mA
Peak Current NOx, COM	
(Pulsed 1ms, 10% Duty Cycle, Max)	±100mA
ESD Rating	
Human Body Model (Per Mil-STD-883, Method 3015.7)	>2.5kV

**Thermal Information**

Thermal Resistance (Typical, Note 2)	$\theta_{JA}$ (°C/W)
16 Ld TSSOP Package	110
16 Ld QSOP Package	160
Maximum Junction Temperature (Plastic Package)	+150°C
Maximum Storage Temperature Range	-65°C to +150°C
Pb-free Reflow Profile	see link below
<a href="http://www.intersil.com/pbfree/Pb-FreeReflow.asp">http://www.intersil.com/pbfree/Pb-FreeReflow.asp</a>	

**Operating Conditions**

Temperature Range	-40°C to +85°C
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**CAUTION:** Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions may adversely impact product reliability and result in failures not covered by warranty.

**NOTES:**

1. Signals on NOx, COM, ADDx, INH exceeding V+ or V- are clamped by internal diodes. Limit forward diode current to maximum current ratings.
2.  $\theta_{JA}$  is measured with the component mounted on a high effective thermal conductivity test board in free air. See Tech Brief TB379 for details.

**Electrical Specifications ±5V Supply**

Test Conditions:  $V_{SUPPLY} = \pm 4.5V$  to  $\pm 5.5V$ , GND = 0V,  $V_{INH} = 2.4V$ ,  $V_{INL} = 0.8V$  (Note 3), Unless Otherwise Specified.

PARAMETER	TEST CONDITIONS	TEMP (°C)	MIN (Notes 4, 8)	TYP	MAX (Notes 4, 8)	UNITS
ANALOG SWITCH CHARACTERISTICS						
Analog Signal Range, V <sub>ANALOG</sub>	(Note 10)	Full	V-	-	V+	V
ON-Resistance, r <sub>ON</sub>	V <sub>S</sub> = ±4.5V, I <sub>COM</sub> = 2mA, V <sub>NO</sub> = 3V (See Figure 5)	25	-	44	60	Ω
		Full	-	-	80	Ω
r <sub>ON</sub> Matching Between Channels, Δr <sub>ON</sub>	V <sub>S</sub> = ±4.5V, I <sub>COM</sub> = 2mA, V <sub>NO</sub> = 3V (Note 5)	25	-	1.3	4	Ω
		Full	-	-	6	Ω
r <sub>ON</sub> Flatness, r <sub>FLAT(ON)</sub>	V <sub>S</sub> = ±4.5V, I <sub>COM</sub> = 2mA, V <sub>NO</sub> = ±3V, 0.1V (Note 6)	25	-	7.5	9	Ω
		Full	-	-	12	Ω
NO OFF Leakage Current, I <sub>NO(OFF)</sub>	V <sub>S</sub> = ±5.5V, V <sub>COM</sub> = ±4.5V, V <sub>NO</sub> = $\overline{+4.5V}$ (Note 7)	25	-	0.02	-	nA
		Full	-	0.2	-	nA
COM OFF Leakage Current, I <sub>COM(OFF)</sub>	V <sub>S</sub> = ±5.5V, V <sub>COM</sub> = ±4.5V, V <sub>NO</sub> = $\overline{+4.5V}$ (Note 7)	25	-	0.02	-	nA
		Full	-	0.2	-	nA
COM ON Leakage Current, I <sub>COM(ON)</sub>	V <sub>S</sub> = ±5.5V, V <sub>COM</sub> = V <sub>NO</sub> = ±4.5V (Note 7)	25	-	0.02	-	nA
		Full	-	0.2	-	nA
DIGITAL INPUT CHARACTERISTICS						
Input Voltage High, V <sub>INHH</sub> , V <sub>ADDH</sub>		Full	2.4	-	-	V
Input Voltage Low, V <sub>INHL</sub> , V <sub>ADDL</sub>		Full	-	-	0.8	V
Input Current, I <sub>ADDH</sub> , I <sub>ADDL</sub> , I <sub>INHH</sub> , I <sub>INHL</sub>	V <sub>S</sub> = ±5.5V, V <sub>INH</sub> , V <sub>ADD</sub> = 0V or V+, (Note 9)	Full	-0.5	-	0.5	μA
DYNAMIC CHARACTERISTICS						
INHIBIT Turn-ON Time, t <sub>ON</sub>	V <sub>S</sub> = ±4.5V, V <sub>NO</sub> = ±3V, R <sub>L</sub> = 300Ω, C <sub>L</sub> = 35pF, V <sub>IN</sub> = 0 to 3 (See Figure 1, Note 9)	25	-	35	50	ns
		Full	-	-	60	ns
INHIBIT Turn-OFF Time, t <sub>OFF</sub>	V <sub>S</sub> = ±4.5V, V <sub>NO</sub> = ±3V, R <sub>L</sub> = 300Ω, C <sub>L</sub> = 35pF, V <sub>IN</sub> = 0 to 3 (See Figure 1, Note 9)	25	-	22	35	ns
		Full	-	-	40	ns
Address Transition Time, t <sub>TRANS</sub>	V <sub>S</sub> = ±4.5V, V <sub>NO</sub> = ±3V, R <sub>L</sub> = 300Ω, C <sub>L</sub> = 35pF, V <sub>IN</sub> = 0 to 3 (See Figure 1, Note 9)	25	-	43	60	ns
		Full	-	-	70	ns

**Electrical Specifications ±5V Supply**

Test Conditions:  $V_{\text{SUPPLY}} = \pm 4.5\text{V to } \pm 5.5\text{V}$ ,  $\text{GND} = 0\text{V}$ ,  $V_{\text{INH}} = 2.4\text{V}$ ,  $V_{\text{INL}} = 0.8\text{V}$  (Note 3),  
Unless Otherwise Specified. **(Continued)**

PARAMETER	TEST CONDITIONS	TEMP (°C)	MIN (Notes 4, 8)	TYP	MAX (Notes 4, 8)	UNITS
Break-Before-Make Time, $t_{\text{BBM}}$	$V_{\text{S}} = \pm 5.5\text{V}$ , $V_{\text{NO}} = 3\text{V}$ , $R_{\text{L}} = 300\Omega$ , $C_{\text{L}} = 35\text{pF}$ , $V_{\text{IN}} = 0$ to $3\text{V}$ (See Figure 3, Note 9)	Full	2	7	-	ns
Charge Injection, $Q$	$C_{\text{L}} = 1.0\text{nF}$ , $V_{\text{G}} = 0\text{V}$ , $R_{\text{G}} = 0\Omega$ (See Figure 2, Note 9)	25	-	0.3	1	pC
NO OFF Capacitance, $C_{\text{OFF}}$	$f = 1\text{MHz}$ , $V_{\text{NO}} = V_{\text{COM}} = 0\text{V}$ (See Figure 6)	25	-	3	-	pF
COM OFF Capacitance, $C_{\text{OFF}}$	$f = 1\text{MHz}$ , $V_{\text{NO}} = V_{\text{COM}} = 0\text{V}$ (See Figure 6)	25	-	21	-	pF
COM ON Capacitance, $C_{\text{COM(ON)}}$	$f = 1\text{MHz}$ , $V_{\text{NO}} = V_{\text{COM}} = 0\text{V}$ (See Figure 6)	25	-	26	-	pF
OFF-Isolation	$R_{\text{L}} = 50\Omega$ , $C_{\text{L}} = 15\text{pF}$ , $f = 100\text{kHz}$ , $V_{\text{NOx}} = 1V_{\text{RMS}}$ (See Figures 4 and 18)	25	-	92	-	dB
<b>POWER SUPPLY CHARACTERISTICS</b>						
Power Supply Range	(Note 10)	Full	$\pm 2$	-	$\pm 6$	V
Positive Supply Current, $I_{+}$	$V_{\text{S}} = \pm 5.5\text{V}$ , $V_{\text{INH}}$ , $V_{\text{ADD}} = 0\text{V}$ or $V_{+}$ , Switch On or Off, (Note 9)	Full	-7	-	7	$\mu\text{A}$
Negative Supply Current, $I_{-}$		Full	-1	-	1	$\mu\text{A}$

**Electrical Specifications +12V Supply**

Test Conditions:  $V_{+} = +10.8\text{V to } +13.2\text{V}$ ,  $\text{GND} = 0\text{V}$ ,  $V_{\text{INH}} = 4\text{V}$ ,  $V_{\text{INL}} = 0.8\text{V}$  (Note 3),  
Unless Otherwise Specified.

PARAMETER	TEST CONDITIONS	TEMP (°C)	MIN (Notes 4, 8)	TYP	MAX (Notes 4, 8)	UNITS
ANALOG SWITCH CHARACTERISTICS						
Analog Signal Range, V <sub>ANALOG</sub>	(Note 10)	Full	0	-	V+	V
ON-Resistance, r <sub>ON</sub>	V+ = 10.8V, I <sub>COM</sub> = 1.0mA, V <sub>NO</sub> = 9V (See Figure 5)	25	-	37	45	Ω
		Full	-	-	55	Ω
r <sub>ON</sub> Matching Between Channels, Δr <sub>ON</sub>	V+ = 10.8V, I <sub>COM</sub> = 1.0mA, V <sub>NO</sub> = 9V (Note 5)	25	-	1.2	2	Ω
		Full	-	-	2	Ω
r <sub>ON</sub> Flatness, r <sub>FLAT(ON)</sub>	V+ = 10.8V, I <sub>COM</sub> = 1.0mA, V <sub>NO</sub> = 3V, 6V, 9V (Note 6)	Full	-	5	-	Ω
NO OFF Leakage Current, I <sub>NO(OFF)</sub>	V+ = 13.2V, V <sub>COM</sub> = 1V, 12V, V <sub>NO</sub> = 12V, 1V (Note 7)	25	-	0.02	-	nA
		Full	-	0.2	-	nA
COM OFF Leakage Current, I <sub>COM(OFF)</sub>	V+ = 13.2V, V <sub>COM</sub> = 12V, 1V, V <sub>NO</sub> = 1V, 12V (Note 7)	25	-	0.02	-	nA
		Full	-	0.2	-	nA
COM ON Leakage Current, I <sub>COM(ON)</sub>	V+ = 13.2V, V <sub>COM</sub> = 1V, 12V, V <sub>NO</sub> = 1V, 12V, or floating (Note 7)	25	-	0.02	-	nA
		Full	-	0.2	-	nA
DIGITAL INPUT CHARACTERISTICS						
Input Voltage High, V <sub>INH<sub>H</sub></sub> , V <sub>ADDH</sub>		Full	3.7	3.3	-	V
Input Voltage Low, V <sub>INH<sub>L</sub></sub> , V <sub>ADDL</sub>		Full	-	2.7	0.8	V
Input Current, I <sub>ADDH</sub> , I <sub>ADDL</sub> , I <sub>INH<sub>H</sub></sub> , I <sub>INH<sub>L</sub></sub>	V+ = 13.2V, V <sub>INH</sub> , V <sub>ADD</sub> = 0V or V+	Full	-0.5	-	0.5	μA
DYNAMIC CHARACTERISTICS						
INHIBIT Turn-ON Time, t <sub>ON</sub>	V+ = 10.8V, V <sub>NO</sub> = 10V, R <sub>L</sub> = 300Ω, C <sub>L</sub> = 35pF, V <sub>IN</sub> = 0 to 4 (See Figure 1, Note 9)	25	-	24	40	ns
		Full	-	-	45	ns
INHIBIT Turn-OFF Time, t <sub>OFF</sub>	V+ = 10.8V, V <sub>NO</sub> = 10V, R <sub>L</sub> = 300Ω, C <sub>L</sub> = 35pF, V <sub>IN</sub> = 0 to 4 (See Figure 1, Note 9)	25	-	15	30	ns
		Full	-	-	35	ns

**Electrical Specifications +12V Supply**

Test Conditions:  $V_+ = +10.8V$  to  $+13.2V$ ,  $GND = 0V$ ,  $V_{INH} = 4V$ ,  $V_{INL} = 0.8V$  (Note 3),  
Unless Otherwise Specified. **(Continued)**

PARAMETER	TEST CONDITIONS	TEMP (°C)	MIN (Notes 4, 8)	TYP	MAX (Notes 4, 8)	UNITS
Address Transition Time, $t_{TRANS}$	$V_+ = 10.8V$ , $V_{NO} = 10V$ , $R_L = 300\Omega$ , $C_L = 35pF$ , $V_{IN} = 0$ to 4 (See Figure 1, Note 9)	25	-	27	50	ns
		Full	-	-	55	ns
Break-Before-Make Time Delay, $t_D$	$V_+ = 13.2V$ , $R_L = 300\Omega$ , $C_L = 35pF$ , $V_{NO} = 10V$ , $V_{IN} = 0$ to 4 (See Figure 3, Note 9)	Full	2	5	-	ns
Charge Injection, $Q$	$C_L = 1.0nF$ , $V_G = 0V$ , $R_G = 0\Omega$ (See Figure 2, Note 9)	25	-	2.7	5	pC
OFF-Isolation	$R_L = 50\Omega$ , $C_L = 15pF$ , $f = 100kHz$ (See Figures 4 and 18)	25	-	92	-	dB
NO OFF Capacitance, $C_{OFF}$	$f = 1MHz$ , $V_{NO} = V_{COM} = 0V$ (See Figure 6)	25	-	3	-	pF
COM OFF Capacitance, $C_{COM(OFF)}$	$f = 1MHz$ , $V_{NO} = V_{COM} = 0V$ (See Figure 6)	25	-	21	-	pF
COM ON Capacitance, $C_{COM(ON)}$	$f = 1MHz$ , $V_{NO} = V_{COM} = 0V$ (See Figure 6)	25	-	26	-	pF
<b>POWER SUPPLY CHARACTERISTICS</b>						
Power Supply Range	(Note 10)	Full	2	-	12	V
Positive Supply Current, $I_+$	$V_+ = 13.2V$ , $V_{INH}$ , $V_{ADD} = 0V$ or $V_+$ , all channels on or off	Full	-7	-	7	$\mu A$

**Electrical Specifications 5V Supply**

Test Conditions:  $V_+ = +4.5V$  to  $+5.5V$ ,  $V_- = GND = 0V$ ,  $V_{INH} = 2.4V$ ,  $V_{INL} = 0.8V$  (Note 3),  
Unless Otherwise Specified.

PARAMETER	TEST CONDITIONS	TEMP (°C)	MIN (Notes 4, 8)	TYP	MAX (Notes 4, 8)	UNITS
ANALOG SWITCH CHARACTERISTICS						
Analog Signal Range, V <sub>ANALOG</sub>	(Note 10)	Full	0	-	V+	V
ON-Resistance, r <sub>ON</sub>	V+ = 4.5V, I <sub>COM</sub> = 1.0mA, V <sub>NO</sub> = 3.5V (See Figure 5)	25	-	81	100	Ω
		Full	-	-	120	Ω
r <sub>ON</sub> Matching Between Channels, Δr <sub>ON</sub>	V+ = 4.5V, I <sub>COM</sub> = 1.0mA, V <sub>NO</sub> = 3V (Note 5)	25	-	2.2	4	Ω
		Full	-	-	6	Ω
r <sub>ON</sub> Flatness, r <sub>FLAT(ON)</sub>	V+ = 4.5V, I <sub>COM</sub> = 1.0mA, V <sub>NO</sub> = 1V, 2V, 3V (Note 6)	Full	-	11.5	-	Ω
NO OFF Leakage Current, I <sub>NO(OFF)</sub>	V+ = 5.5V, V <sub>COM</sub> = 1V, 4.5V, V <sub>NO</sub> = 4.5V, 1V (Note 7)	25	-	0.02	-	nA
		Full	-	0.2	-	nA
COM OFF Leakage Current, I <sub>COM(OFF)</sub>	V+ = 5.5V, V <sub>COM</sub> = 1V, 4.5V, V <sub>NO</sub> = 4.5V, 1V (Note 7)	25	-	0.02	-	nA
		Full	-	0.2	-	nA
COM ON Leakage Current, I <sub>COM(ON)</sub>	V+ = 5.5V, V <sub>COM</sub> = V <sub>NO</sub> = 4.5V (Note 7)	25	-	0.02	-	nA
		Full	-	0.2	-	nA
DIGITAL INPUT CHARACTERISTICS						
Input Voltage High, V <sub>INHH</sub> , V <sub>ADDH</sub>		Full	2.4	-	-	V
Input Voltage Low, V <sub>INHL</sub> , V <sub>ADDL</sub>		Full	-	-	0.8	V
Input Current, I <sub>ADDH</sub> , I <sub>ADDL</sub> , I <sub>INH</sub> , I <sub>INHL</sub>	V+ = 5.5V, V <sub>INH</sub> , V <sub>ADD</sub> = 0V or V+, (Note 9)	Full	-0.5	-	0.5	μA
DYNAMIC CHARACTERISTICS						
INHIBIT Turn-ON Time, t <sub>ON</sub>	V+ = 4.5V, V <sub>NO</sub> = 3V, R <sub>L</sub> = 300Ω, C <sub>L</sub> = 35pF, V <sub>IN</sub> = 0 to 3V (see Figure 1, Note 9)	25	-	43	60	ns
		Full	-	-	70	ns

**Electrical Specifications 5V Supply**

Test Conditions:  $V_+ = +4.5V$  to  $+5.5V$ ,  $V_- = GND = 0V$ ,  $V_{INH} = 2.4V$ ,  $V_{INL} = 0.8V$  (Note 3),  
Unless Otherwise Specified. **(Continued)**

PARAMETER	TEST CONDITIONS	TEMP (°C)	MIN (Notes 4, 8)	TYP	MAX (Notes 4, 8)	UNITS
INHIBIT Turn-OFF Time, $t_{OFF}$	$V_+ = 4.5V$ , $V_{NO} = 3V$ , $R_L = 300\Omega$ , $C_L = 35pF$ , $V_{IN} = 0$ to $3V$ (see Figure 1, Note 9)	25	-	20	35	ns
		Full	-	-	40	ns
Address Transition Time, $t_{TRANS}$	$V_+ = 4.5V$ , $V_{NO} = 3V$ , $R_L = 300\Omega$ , $C_L = 35pF$ , $V_{IN} = 0$ to $3V$ (see Figure 1, Note 9)	25	-	51	70	ns
		Full	-	-	85	ns
Break-Before-Make Time, $t_{BBM}$	$V_+ = 5.5V$ , $V_{NO} = 3V$ , $R_L = 300\Omega$ , $C_L = 35pF$ , $V_{IN} = 0$ to $3V$ (see Figure 3, Note 9)	Full	2	9	-	ns
Charge Injection, $Q$	$C_L = 1.0nF$ , $V_G = 0V$ , $R_G = 0\Omega$ (see Figure 2, Note 9)	25	-	0.6	1.5	pC
OFF-Isolation	$R_L = 50\Omega$ , $C_L = 15pF$ , $f = 100kHz$ , $V_{NOx} = 1V_{RMS}$ (see Figures 4 and 18)	25	-	92	-	dB
<b>POWER SUPPLY CHARACTERISTICS</b>						
Power Supply Range	(Note 10)	Full	2	-	12	V
Positive Supply Current, $I_+$	$V_+ = 5.5V$ , $V_- = 0V$ , $V_{INH}$ , $V_{ADD} = 0V$ or $V_+$ , Switch On or Off, (Note 9)	Full	-7	-	7	$\mu A$
Positive Supply Current, $I_-$		Full	-1	-	1	$\mu A$

**Electrical Specifications 3.3V Supply** Test Conditions:  $V_+ = +3.0V$  to  $+3.6V$ ,  $V_- = GND = 0V$ ,  $V_{INH} = 2.4V$ ,  $V_{INL} = 0.8V$  (Note 3),  
Unless Otherwise Specified

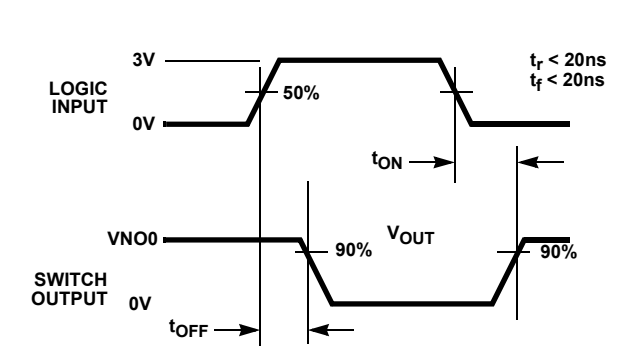
PARAMETER	TEST CONDITIONS	TEMP (°C)	MIN (Notes 4, 8)	TYP	MAX (Notes 4, 8)	UNITS
ANALOG SWITCH CHARACTERISTICS						
Analog Signal Range, V <sub>ANALOG</sub>		Full	0	-	V+	V
ON-Resistance, r <sub>ON</sub>	V+ = 3.0V, I <sub>COM</sub> = 1.0mA, V <sub>NO</sub> = 1.5V (see Figure 5)	25	-	135	180	Ω
		Full	-	-	200	Ω
r <sub>ON</sub> Matching Between Channels, Δr <sub>ON</sub>	V+ = 3.0V, I <sub>COM</sub> = 1.0mA, V <sub>NO</sub> = 1.5V (Note 5)	25	-	3.4	8	Ω
		Full	-	-	10	Ω
r <sub>ON</sub> Flatness, r <sub>FLAT(ON)</sub>	V+ = 3.0V, I <sub>COM</sub> = 1.0mA, V <sub>NO</sub> = 0.5V, 1V, 2V (Note 6)	Full	-	34	-	Ω
NO OFF Leakage Current, I <sub>NO(OFF)</sub>	V+ = 3.6V, V <sub>COM</sub> = 0V, 4.5V, V <sub>NO</sub> = 3V, 1V (Note 7)	25	-	0.02	-	nA
		Full	-	0.2	-	nA
COM OFF Leakage Current, I <sub>COM(OFF)</sub>	V+ = 3.6V, V <sub>COM</sub> = 0V, 4.5V, V <sub>NO</sub> = 3V, 1V (Note 7)	25	-	0.02	-	nA
		Full	-	0.2	-	nA
COM ON Leakage Current, I <sub>COM(ON)</sub>	V+ = 3.6V, V <sub>COM</sub> = V <sub>NO</sub> = 3V (Note 7)	25	-	0.02	-	nA
		Full	-	0.2	-	nA
DIGITAL INPUT CHARACTERISTICS						
Input Voltage High, V <sub>INHh</sub> , V <sub>ADDh</sub>		Full	2.4	-	-	V
Input Voltage Low, V <sub>INLh</sub> , V <sub>ADDL</sub>		Full	-	-	0.8	V
Input Current, I <sub>ADDh</sub> , I <sub>ADDL</sub> , I <sub>INHh</sub> , I <sub>INLh</sub>	V+ = 3.6V, V <sub>INH</sub> , V <sub>ADD</sub> = 0V or V+, (Note 9)	Full	-0.5	-	0.5	μA
DYNAMIC CHARACTERISTICS						
INHIBIT Turn-ON Time, t <sub>ON</sub>	V+ = 3.0V, V <sub>NO</sub> = 1.5V, R <sub>L</sub> = 300Ω, C <sub>L</sub> = 35pF, V <sub>IN</sub> = 0V to 3V (see Figure 1, Note 9)	25	-	82	100	ns
		Full	-	-	120	ns

**Electrical Specifications 3.3V Supply** Test Conditions: V+ = +3.0V to +3.6V, V- = GND = 0V, VINH = 2.4V, VINL = 0.8V (Note 3), Unless Otherwise Specified **(Continued)**

PARAMETER	TEST CONDITIONS	TEMP (°C)	MIN (Notes 4, 8)	TYP	MAX (Notes 4, 8)	UNITS
INHIBIT Turn-OFF Time, tOFF	V+ = 3.0V, VNO = 1.5V, RL = 300Ω, CL = 35pF, VIN = 0V to 3V (see Figure 1, Note 9)	25	-	37	50	ns
		Full	-	-	60	ns
Address Transition Time, tTRANS	V+ = 3.0V, VNO = 1.5V, RL = 300Ω, CL = 35pF, VIN = 0V to 3V (see Figure 1, Note 9)	25	-	96	120	ns
		Full	-	-	145	ns
Break-Before-Make Time, tBBM	V+ = 3.6V, VNO = 1.5V, RL = 300Ω, CL = 35pF, VIN = 0V to 3V (see Figure 3, Note 9)	Full	3	13	-	ns
Charge Injection, Q	CL = 1.0nF, VG = 0V, RG = 0Ω (see Figure 2, Note 9)	25	-	0.3	1	pC
OFF-Isolation	RL = 50Ω, CL = 15pF, f = 100kHz, VNO = 1VRMS (see Figures 4 and 18)	25	-	92	-	dB
<b>POWER SUPPLY CHARACTERISTICS</b>						
Power Supply Range	(Note 10)	Full	2	-	12	V

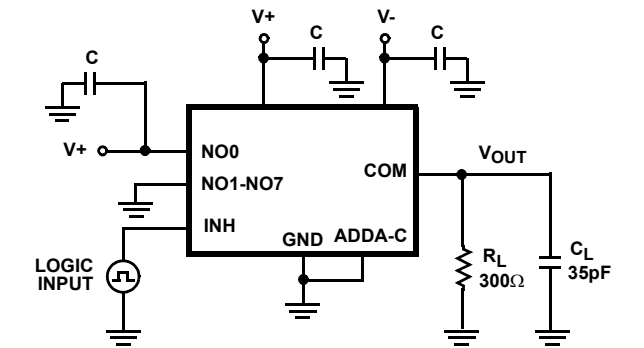
- NOTES:
- 3. VIN = Input logic voltage to configure the device in a given state.
  - 4. The algebraic convention, whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
  - 5. ΔrON = rON (MAX) - rON (MIN).
  - 6. Flatness is defined as the difference between maximum and minimum value of on-resistance over the specified analog signal range.
  - 7. Leakage parameter is 100% tested at high temp, and guaranteed by correlation at +25°C.
  - 8. Parameters with MIN and/or MAX limits are 100% tested at +25°C, unless otherwise specified. Temperature limits established by characterization and are not production tested.
  - 9. Limits established by characterization and are not production tested.
  - 10. Limits should be considered typical and are not production tested.

**Test Circuits and Waveforms**



Logic input waveform is inverted for switches that have the opposite logic sense.

FIGURE 1A. INHIBIT tON/tOFF MEASUREMENT POINTS

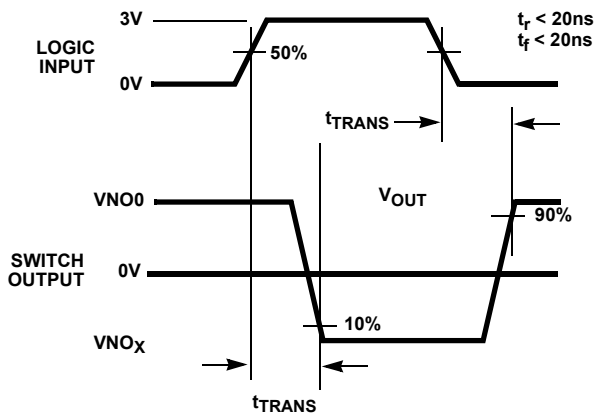


Repeat test for other switches. CL includes fixture and stray capacitance.

$$V_{OUT} = V_{(NO \text{ or } NC)} \frac{R_L}{R_L + r_{ON}}$$

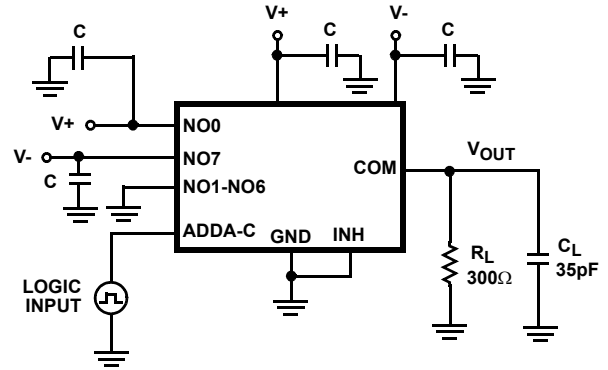
FIGURE 1B. INHIBIT tON/tOFF TEST CIRCUIT

## Test Circuits and Waveforms (Continued)



Logic input waveform is inverted for switches that have the opposite logic sense.

FIGURE 1C. ADDRESS  $t_{TRANS}$  MEASUREMENT POINTS



Repeat test for other switches.  $C_L$  includes fixture and stray capacitance.

$$V_{OUT} = V_{(NO \text{ or } NC)} \frac{R_L}{R_L + r_{ON}}$$

FIGURE 1D. ADDRESS  $t_{TRANS}$  TEST CIRCUIT

FIGURE 1. SWITCHING TIMES

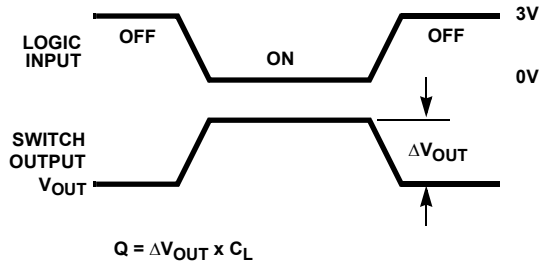
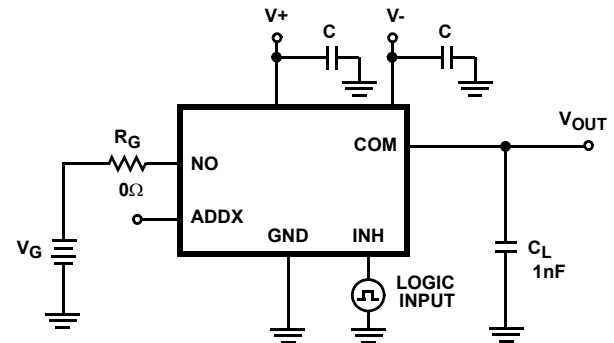


FIGURE 2A. Q MEASUREMENT POINTS



Repeat test for other switches.

FIGURE 2B. Q TEST CIRCUIT

FIGURE 2. CHARGE INJECTION

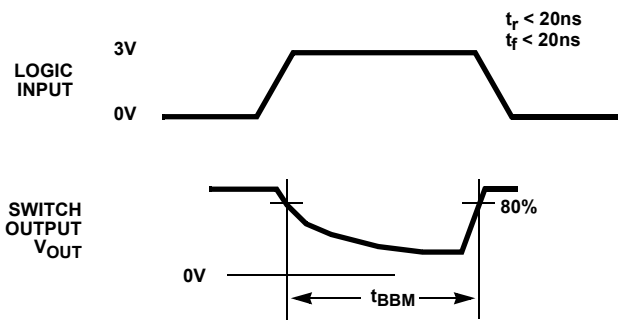
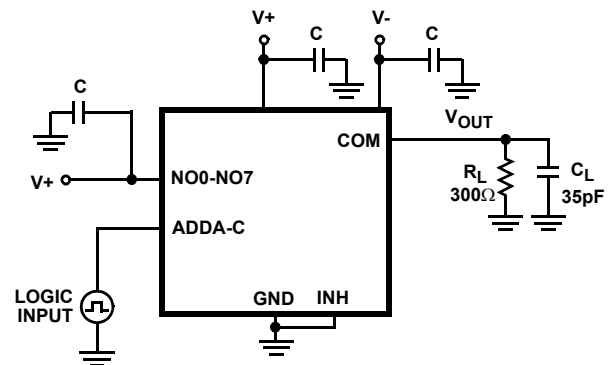


FIGURE 3A.  $t_{BBM}$  MEASUREMENT POINTS



Repeat test for other switches.  $C_L$  includes fixture and stray capacitance.

FIGURE 3B.  $t_{BBM}$  TEST CIRCUIT

FIGURE 3. BREAK-BEFORE-MAKE TIME



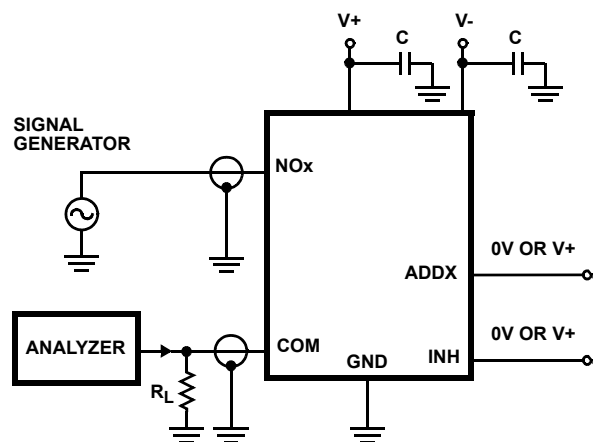
**Test Circuits and Waveforms** (Continued)

FIGURE 4. OFF-ISOLATION TEST CIRCUIT

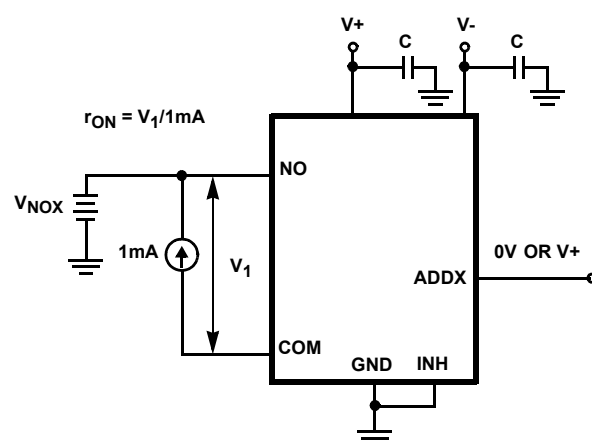
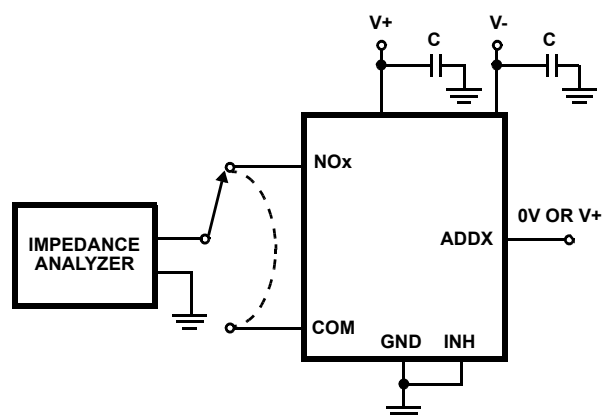
FIGURE 5.  $r_{ON}$  TEST CIRCUIT

FIGURE 6. CAPACITANCE TEST CIRCUIT

## Detailed Description

The ISL84581 multiplexer offers precise switching capability from bipolar  $\pm 2\text{V}$  to  $\pm 6\text{V}$  supplies or a single  $2\text{V}$  to  $12\text{V}$  supply. When powered with dual  $\pm 5\text{V}$  supplies the part has low ON-resistance ( $39\Omega$ ) and high speed operation ( $t_{\text{ON}} = 38\text{ns}$ ,  $t_{\text{OFF}} = 19\text{ns}$ ).

It has an inhibit pin to simultaneously open all signal paths.

The device is especially well suited for applications using  $\pm 5\text{V}$  supplies. With  $\pm 5\text{V}$  supplies the performance ( $r_{\text{ON}}$ , Leakage, Charge Injection, etc.) is best in class.

High frequency applications also benefit from the wide bandwidth and high off-isolation.

### Supply Sequencing And Overvoltage Protection

With any CMOS device, proper power supply sequencing is required to protect the device from excessive input currents which might permanently damage the IC. All I/O pins contain ESD protection diodes from the pin to  $V+$  and to  $V-$  (see Figure 7). To prevent forward biasing these diodes,  $V+$  and  $V-$  must be applied before any input signals, and input signal voltages must remain between  $V+$  and  $V-$ . If these conditions cannot be guaranteed, then one of the following two protection methods should be employed.

Logic inputs can easily be protected by adding a  $1\text{k}\Omega$  resistor in series with the input (see Figure 7). The resistor limits the input current below the threshold that produces permanent damage, and the sub-microamp input current produces an insignificant voltage drop during normal operation.

This method is not applicable for the signal path inputs. Adding a series resistor to the switch input defeats the purpose of using a low  $r_{\text{ON}}$  switch, so two small signal diodes can be added in series with the supply pins to provide overvoltage protection for all pins (see Figure 7). These additional diodes limit the analog signal from  $1\text{V}$  below  $V+$  to  $1\text{V}$  above  $V-$ . The low leakage current performance is unaffected by this approach, but the switch resistance may increase, especially at low supply voltages.

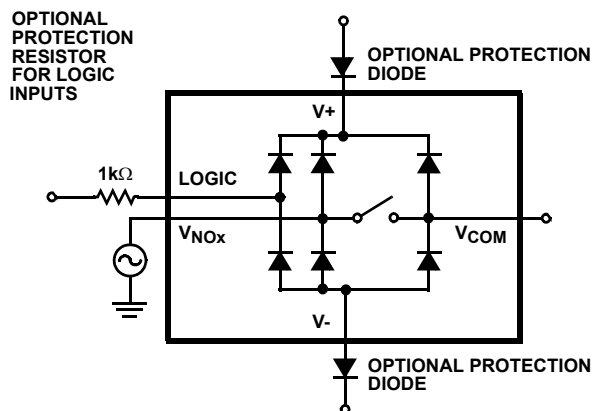


FIGURE 7. INPUT OVERVOLTAGE PROTECTION

## Power-Supply Considerations

The ISL84581 construction is typical of most CMOS analog switches, in that it has three supply pins:  $V+$ ,  $V-$ , and GND.  $V+$  and  $V-$  drive the internal CMOS switches and set their analog voltage limits, so there are no connections between the analog signal path and GND. Unlike switches with a  $13\text{V}$  maximum supply voltage, the ISL84581  $15\text{V}$  maximum supply voltage provides plenty of room for the 10% tolerance of  $12\text{V}$  supplies ( $\pm 6\text{V}$  or  $12\text{V}$  single supply), as well as room for overshoot and noise spikes.

The part performs equally well when operated with bipolar or single voltage supplies. The minimum recommended supply voltage is  $2\text{V}$  single supply or  $\pm 2\text{V}$  dual supply. It is important to note that the input signal range, switching times, and ON-resistance degrade at lower supply voltages. Refer to the "Electrical Specification" tables on page 4 and "Typical Performance Curves" on page 11 for details.

$V+$  and GND power the internal logic setting the digital switching point of the level shifters. The level shifters convert the logic levels to switched  $V+$  and  $V-$  signals to drive the analog switch gate terminals.

### Logic-Level Thresholds

$V+$  and GND power the internal logic stages, so  $V-$  has no affect on logic thresholds. This ISL84581 is TTL compatible ( $0.8\text{V}$  and  $2.4\text{V}$ ) over a  $V+$  supply range of  $2.7\text{V}$  to  $10\text{V}$ . At  $12\text{V}$  the  $V_{\text{IH}}$  level is about  $3.3\text{V}$ . This is still below the CMOS guaranteed high output minimum level of  $4\text{V}$ , but noise margin is reduced. For best results with a  $12\text{V}$  supply, use a logic family that provides a  $V_{\text{OH}}$  greater than  $4\text{V}$ .

The digital input stages draw supply current whenever the digital input voltage is not at one of the supply rails. Driving the digital input signals from GND to  $V+$  with a fast transition time minimizes power dissipation.

### High-Frequency Performance

In  $50\Omega$  systems, signal response is reasonably flat even past  $100\text{MHz}$  (see Figures 16 and 17). Figures 16 and 17 also illustrate that the frequency response is very consistent over varying analog signal levels.

An OFF switch acts like a capacitor and passes higher frequencies with less attenuation, resulting in signal feed through from a switch's input to its output. Off-isolation is the resistance to this feed through. Figure 18 details the high off isolation of the ISL84581. At  $10\text{MHz}$ , off-isolation is about  $55\text{dB}$  in  $50\Omega$  systems, decreasing approximately  $20\text{dB}$  per decade as frequency increases. Higher load impedances decrease off-isolation due to the voltage divider action of the switch OFF impedance and the load impedance.

## Leakage Considerations

Reverse ESD protection diodes are internally connected between each analog-signal pin and both V+ and V-. One of these diodes conducts if any analog signal exceeds V+ or V-.

Virtually all the analog leakage current comes from the ESD diodes to V+ or V-. Although the ESD diodes on a given signal pin are identical and therefore fairly well balanced, they are reverse biased differently. Each is biased by either

V+ or V- and the analog signal. This means their leakages will vary as the signal varies. The difference in the two diode leakages to the V+ and V- pins constitutes the analog-signal-path leakage current. All analog leakage current flows between each pin and one of the supply terminals, not to the other switch terminal. This is why both sides of a given switch can show leakage currents of the same or opposite polarity. There is no connection between the analog signal paths and GND.

## Typical Performance Curves $T_A = +25^\circ\text{C}$ , Unless Otherwise Specified

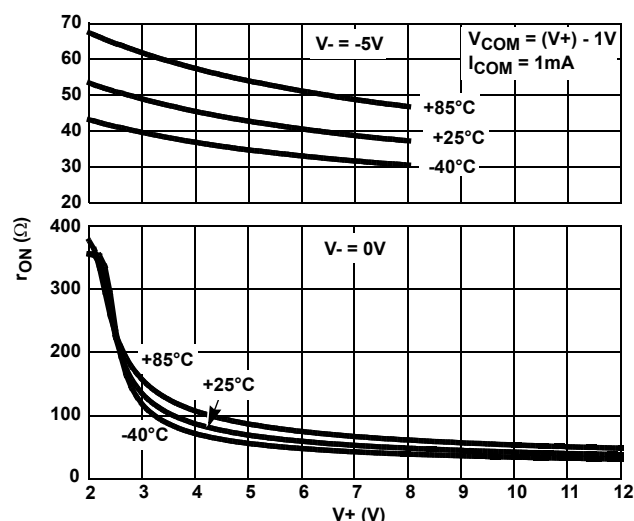


FIGURE 8. ON-RESISTANCE vs SUPPLY VOLTAGE

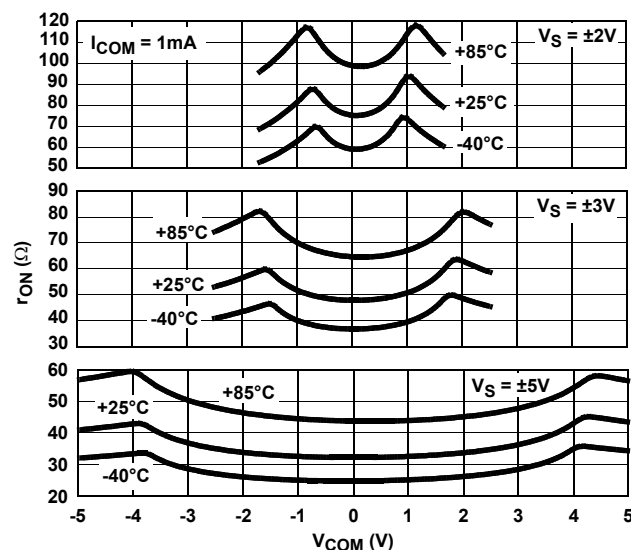


FIGURE 9. ON-RESISTANCE vs SWITCH VOLTAGE

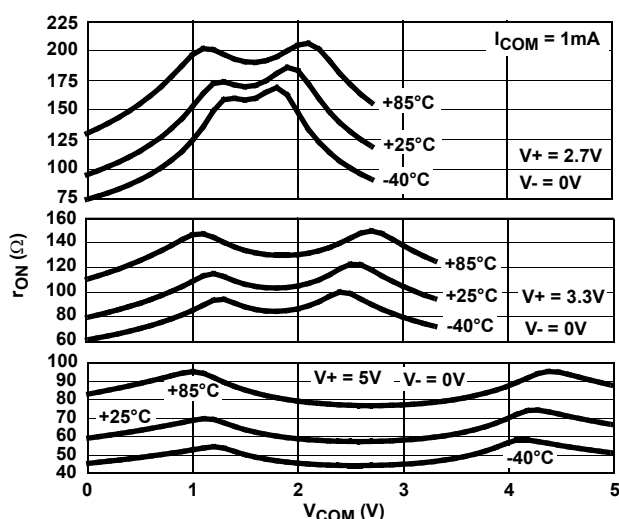


FIGURE 10. ON-RESISTANCE vs SWITCH VOLTAGE

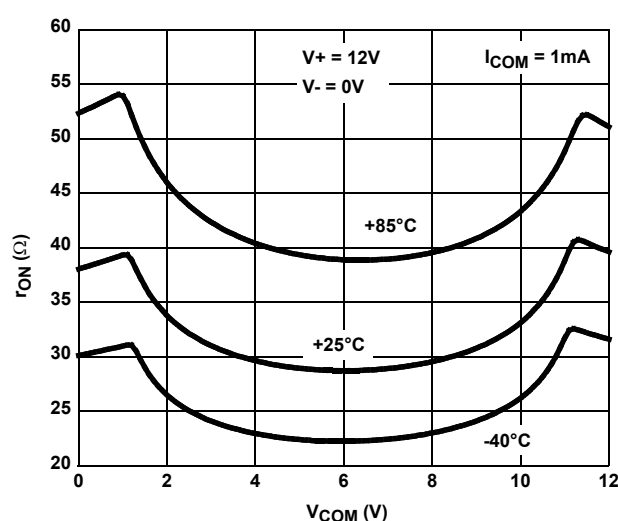


FIGURE 11. ON-RESISTANCE vs SWITCH VOLTAGE

# Typical Performance Curves $T_A = +25^\circ\text{C}$ , Unless Otherwise Specified (Continued)

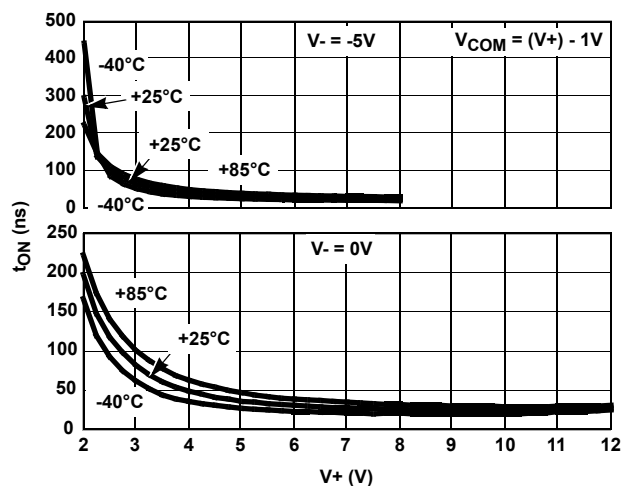


FIGURE 12. INHIBIT TURN-ON TIME vs SUPPLY VOLTAGE

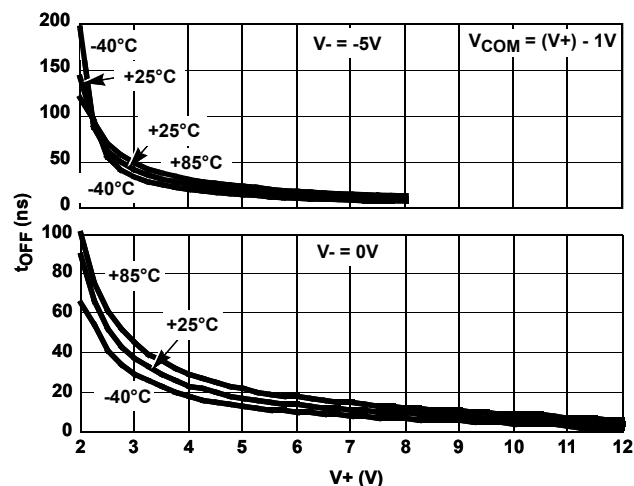


FIGURE 13. INHIBIT TURN-OFF TIME vs SUPPLY VOLTAGE

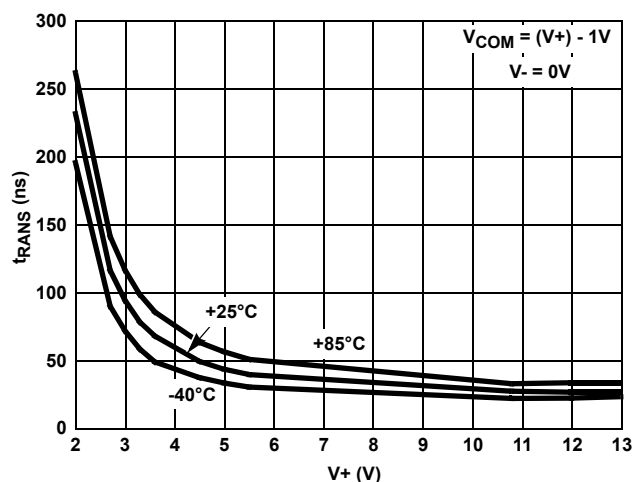


FIGURE 14. ADDRESS TRANS TIME vs SINGLE SUPPLY VOLTAGE

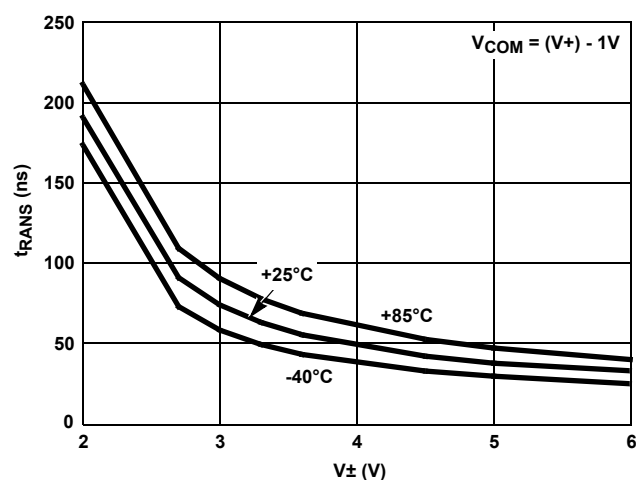


FIGURE 15. ADDRESS TRANS TIME vs DUAL SUPPLY VOLTAGE

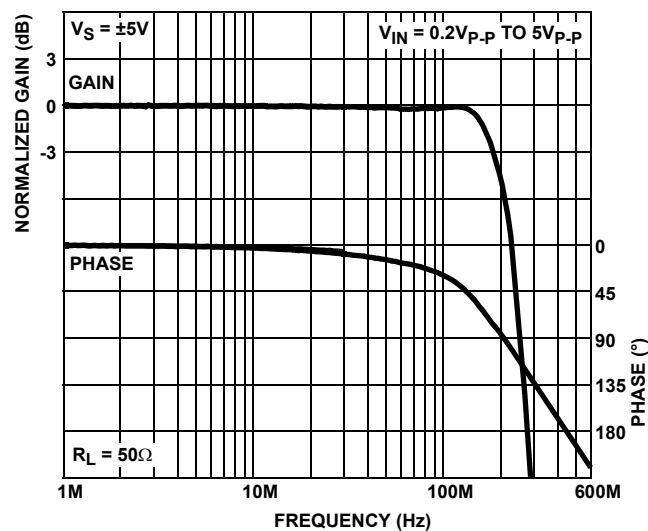


FIGURE 16. FREQUENCY RESPONSE

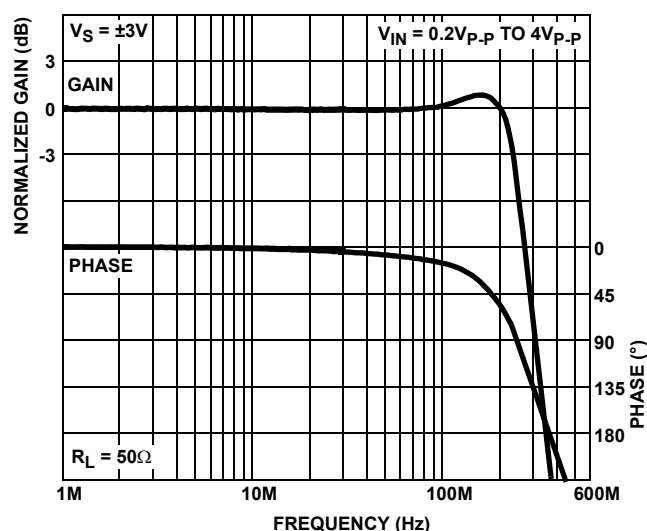


FIGURE 17. FREQUENCY RESPONSE

### Typical Performance Curves $T_A = +25^\circ\text{C}$ , Unless Otherwise Specified (Continued)

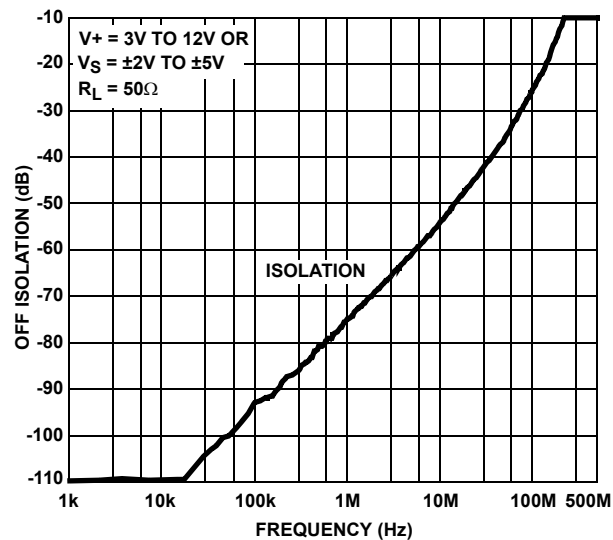


FIGURE 18. OFF ISOLATION

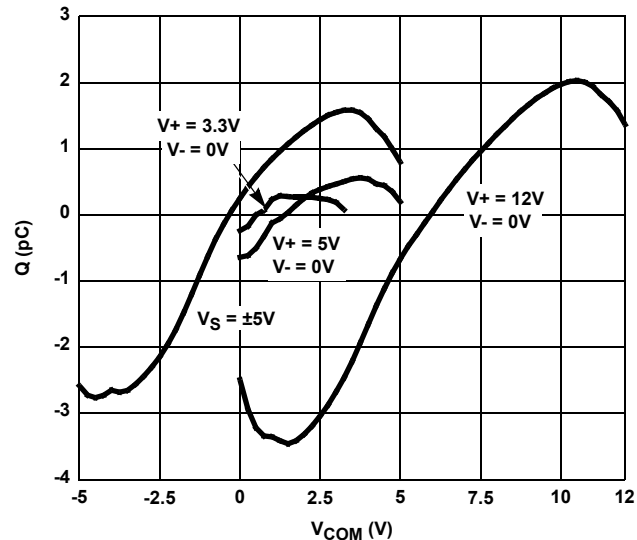


FIGURE 19. CHARGE INJECTION vs SWITCH VOLTAGE

### Die Characteristics

SUBSTRATE POTENTIAL (POWERED UP):

$V_-$

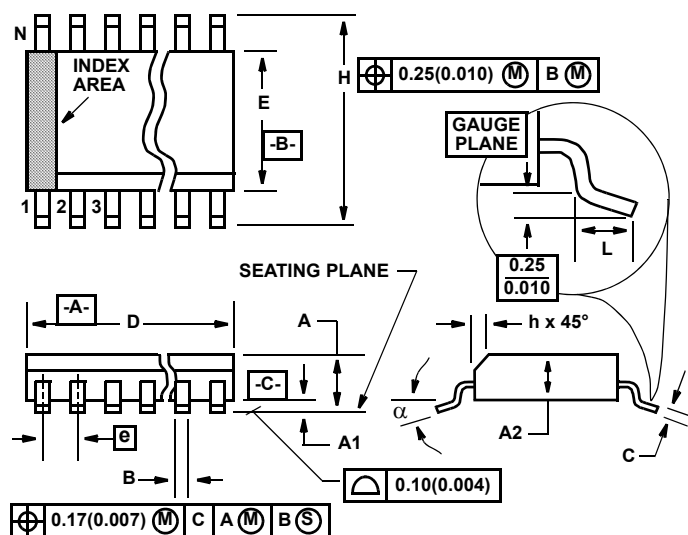
TRANSISTOR COUNT:

193

PROCESS:

Si Gate CMOS

## Shrink Small Outline Plastic Packages (SSOP) Quarter Size Outline Plastic Packages (QSOP)



### NOTES:

1. Symbols are defined in the "MO Series Symbol List" in Section 2.2 of Publication Number 95.
2. Dimensioning and tolerancing per ANSI Y14.5M-1982.
3. Dimension "D" does not include mold flash, protrusions or gate burrs. Mold flash, protrusion and gate burrs shall not exceed 0.15mm (0.006 inch) per side.
4. Dimension "E" does not include interlead flash or protrusions. Interlead flash and protrusions shall not exceed 0.25mm (0.010 inch) per side.
5. The chamfer on the body is optional. If it is not present, a visual index feature must be located within the crosshatched area.
6. "L" is the length of terminal for soldering to a substrate.
7. "N" is the number of terminal positions.
8. Terminal numbers are shown for reference only.
9. Dimension "B" does not include dambar protrusion. Allowable dambar protrusion shall be 0.10mm (0.004 inch) total in excess of "B" dimension at maximum material condition.
10. Controlling dimension: INCHES. Converted millimeter dimensions are not necessarily exact.

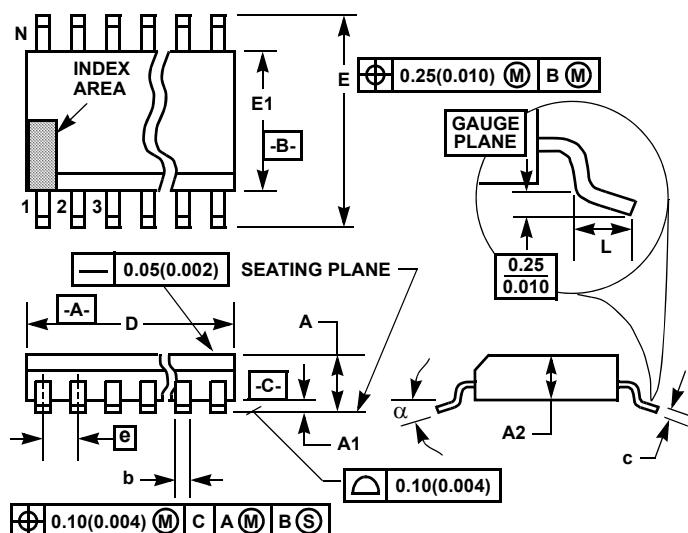
### M16.15A

16 LEAD SHRINK SMALL OUTLINE PLASTIC PACKAGE  
(0.150" WIDE BODY)

SYMBOL	INCHES		MILLIMETERS		NOTES
	MIN	MAX	MIN	MAX	
A	0.061	0.068	1.55	1.73	-
A1	0.004	0.0098	0.102	0.249	-
A2	0.055	0.061	1.40	1.55	-
B	0.008	0.012	0.20	0.31	9
C	0.0075	0.0098	0.191	0.249	-
D	0.189	0.196	4.80	4.98	3
E	0.150	0.157	3.81	3.99	4
e	0.025 BSC		0.635 BSC		-
H	0.230	0.244	5.84	6.20	-
h	0.010	0.016	0.25	0.41	5
L	0.016	0.035	0.41	0.89	6
N	16		16		7
$\alpha$	0°	8°	0°	8°	-

Rev. 2 6/04

## Thin Shrink Small Outline Plastic Packages (TSSOP)



### NOTES:

1. These package dimensions are within allowable dimensions of JEDEC MO-153-AB, Issue E.
2. Dimensioning and tolerancing per ANSI Y14.5M-1982.
3. Dimension "D" does not include mold flash, protrusions or gate burrs. Mold flash, protrusion and gate burrs shall not exceed 0.15mm (0.006 inch) per side.
4. Dimension "E1" does not include interlead flash or protrusions. Interlead flash and protrusions shall not exceed 0.15mm (0.006 inch) per side.
5. The chamfer on the body is optional. If it is not present, a visual index feature must be located within the crosshatched area.
6. "L" is the length of terminal for soldering to a substrate.
7. "N" is the number of terminal positions.
8. Terminal numbers are shown for reference only.
9. Dimension "b" does not include dambar protrusion. Allowable dambar protrusion shall be 0.08mm (0.003 inch) total in excess of "b" dimension at maximum material condition. Minimum space between protrusion and adjacent lead is 0.07mm (0.0027 inch).
10. Controlling dimension: MILLIMETER. Converted inch dimensions are not necessarily exact. (Angles in degrees)

### M16.173

#### 16 LEAD THIN SHRINK SMALL OUTLINE PLASTIC PACKAGE

SYMBOL	INCHES		MILLIMETERS		NOTES
	MIN	MAX	MIN	MAX	
A	-	0.043	-	1.10	-
A1	0.002	0.006	0.05	0.15	-
A2	0.033	0.037	0.85	0.95	-
b	0.0075	0.012	0.19	0.30	9
c	0.0035	0.008	0.09	0.20	-
D	0.193	0.201	4.90	5.10	3
E1	0.169	0.177	4.30	4.50	4
e	0.026 BSC		0.65 BSC		-
E	0.246	0.256	6.25	6.50	-
L	0.020	0.028	0.50	0.70	6
N	16		16		7
α	0°	8°	0°	8°	-

Rev. 1 2/02

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